

# MOSFET - Power, Single N-Channel, Logic Level, SO-8FL

## 40 V, 0.49 mΩ, 455 A

### NTMFS0D5N04XL

#### Features

- Low  $R_{DS(on)}$  to Minimize Conduction Loss
- Low  $Q_{RR}$  with Soft Recovery to Minimize  $E_{RR}$  Loss and Voltage Spike
- Low  $Q_G$  and Capacitance to Minimize Driving and Switching Loss
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### Typical Applications

- High Switching Frequency DC-DC Conversion
- Synchronous Rectification

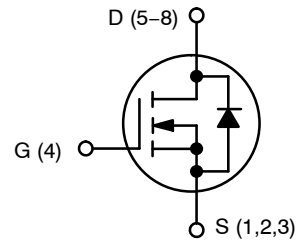
#### MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ unless otherwise stated)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		$V_{DSS}$	40	V	
Gate-to-Source Voltage		$V_{GS}$	$\pm 20$	V	
Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady State	$I_D$	$T_C = 25^\circ\text{C}$	455	A
			$T_C = 100^\circ\text{C}$	322	
Power Dissipation $R_{\theta JC}$ (Note 2)	Steady State	$P_D$	$T_C = 25^\circ\text{C}$	194	W
			$T_C = 100^\circ\text{C}$	97.3	
Pulsed Drain Current	$T_A = 25^\circ\text{C}, t_p = 100 \mu\text{s}$	$I_{DM}$	2474	A	
Pulsed Sourced Current (Body Diode)		$I_{SM}$	2474		
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55 to +175	$^\circ\text{C}$	
Source Current (Body Diode)		$I_S$	306	A	
Single Pulse Drain-to-Source Avalanche Energy ( $I_{Lpk} = 94 \text{ A}$ )		$E_{AS}$	1325	mJ	
Lead Temperature Soldering Reflow for Soldering Purposes (1/8" from case for 10 s)		$T_L$	260	$^\circ\text{C}$	

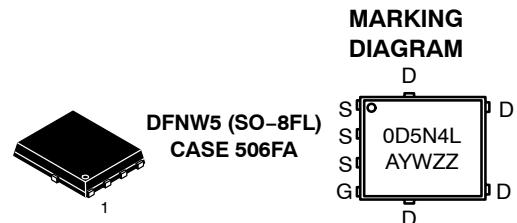
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in<sup>2</sup> pad size, 1 oz Cu pad.
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
3.  $R_{\theta JCT}$  Thermal Resistance - Junction to Case Top = 20  $^\circ\text{C}/\text{W}$ .

$V_{(BR)DSS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
40 V	0.49 mΩ @ 10 V	455 A
	0.78 mΩ @ 4.5 V	



N-CHANNEL MOSFET



0D5N4L = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 W = Work Week  
 ZZ = Lot Traceability

#### ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

# NTMFS0D5N04XL

## THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case – Steady State (Note 2)	$R_{\theta JC}$	0.77	°C/W
Thermal Resistance, Junction-to-Ambient – Steady State (Note 2)	$R_{\theta JA}$	38	

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}, I_D = 1\text{ mA}$	40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	$\Delta V_{(BR)DSS} / \Delta T_J$	$I_D = 1\text{ mA}$ , referenced to $25^\circ\text{C}$		16.5		mV/°C
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{GS} = 0\text{ V}, V_{DS} = 40\text{ V}$	$T_J = 25^\circ\text{C}$		10	$\mu\text{A}$
			$T_J = 125^\circ\text{C}$		100	
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = 20\text{ V}$			100	nA

## ON CHARACTERISTICS

Drain-to-Source On Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 50\text{ A}, T_J = 25^\circ\text{C}$		0.39	0.49	m $\Omega$
		$V_{GS} = 4.5\text{ V}, I_D = 50\text{ A}, T_J = 25^\circ\text{C}$		0.54	0.78	
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS} = V_{DS}, I_D = 330\text{ }\mu\text{A}, T_J = 25^\circ\text{C}$	1.3		2.2	V
Gate Threshold Voltage Temperature Coefficient	$\Delta V_{GS(TH)} / \Delta T_J$	$V_{GS} = V_{DS}, I_D = 330\text{ }\mu\text{A}$		-5.35		mV/°C
Forward Transconductance	$g_{FS}$	$V_{DS} = 5\text{ V}, I_D = 50\text{ A}$		277		S

## CHARGES, CAPACITANCES & GATE RESISTANCE

Input Capacitance	$C_{ISS}$	$V_{GS} = 0\text{ V}, V_{DS} = 20\text{ V}, f = 1\text{ MHz}$		9444		pF
Output Capacitance	$C_{OSS}$			2468		
Reverse Transfer Capacitance	$C_{RSS}$			38		
Output Charge	$Q_{OSS}$	$V_{GS} = 0\text{ V}, V_{DS} = 20\text{ V}$		95		nC
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS} = 4.5\text{ V}, V_{DS} = 20\text{ V}; I_D = 50\text{ A}$		57		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS} = 10\text{ V}, V_{DS} = 20\text{ V}; I_D = 50\text{ A}$		127		
Threshold Gate Charge	$Q_{G(TH)}$			15		
Gate-to-Source Charge	$Q_{GS}$			27		
Gate-to-Drain Charge	$Q_{GD}$			9		
Gate Plateau Voltage	$V_{GP}$			2.8		
Gate Resistance	$R_G$	$f = 1\text{ MHz}$		0.48		

## SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	$t_{d(ON)}$	Resistive Load, $V_{GS} = 0/10\text{ V}, V_{DS} = 20\text{ V},$ $I_D = 50\text{ A}, R_G = 2.5\text{ }\Omega$		11		ns
Rise Time	$t_r$			10		
Turn-Off Delay Time	$t_{d(OFF)}$			55		
Fall Time	$t_f$			24		

## DIODE CHARACTERISTICS

Forward Diode Voltage	$V_{SD}$	$V_{GS} = 0\text{ V}, I_S = 50\text{ A}$	$T_J = 25^\circ\text{C}$		0.78	1.2	V
			$T_J = 125^\circ\text{C}$		0.63		
Reverse Recovery Time	$t_{RR}$	$V_{GS} = 0\text{ V}, V_{DS} = 20\text{ V},$ $di_S/dt = 300\text{ A}/\mu\text{s}, I_S = 50\text{ A}$		40.5		ns	
Charge Time	$t_a$			22.2			
Discharge Time	$t_b$			18.3			
Reverse Recovery Charge	$Q_{RR}$			108			nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Switching characteristics are independent of operating junction temperatures.

# NTMFS0D5N04XL

## TYPICAL CHARACTERISTICS

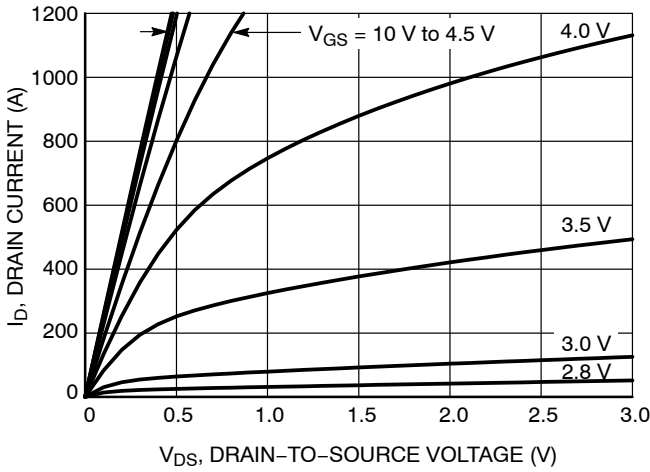


Figure 1. On-Region Characteristics

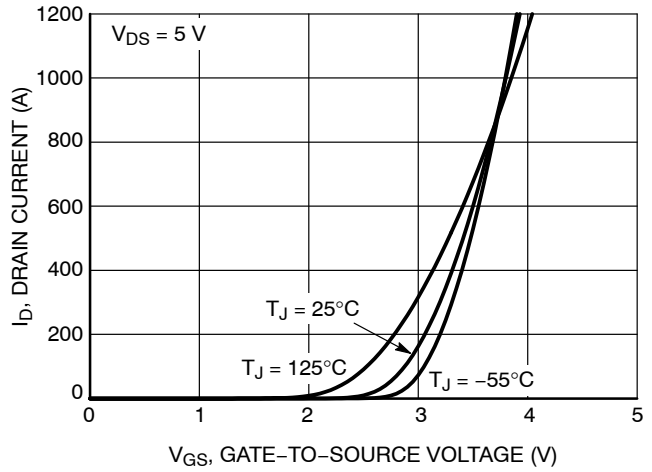


Figure 2. Transfer Characteristics

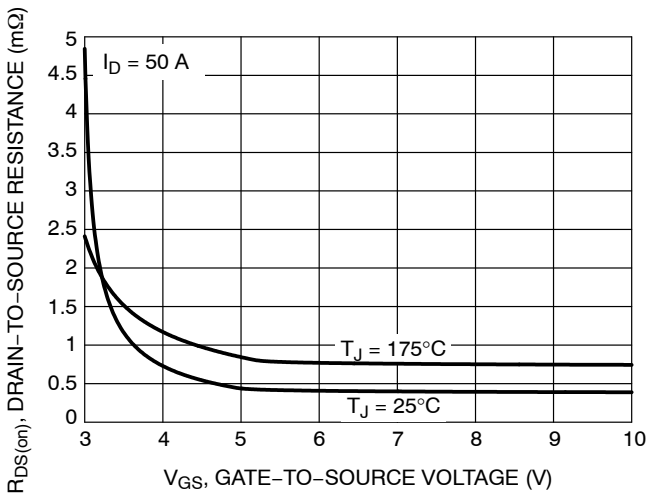


Figure 3. On-Resistance vs. Gate-to-Source Voltage

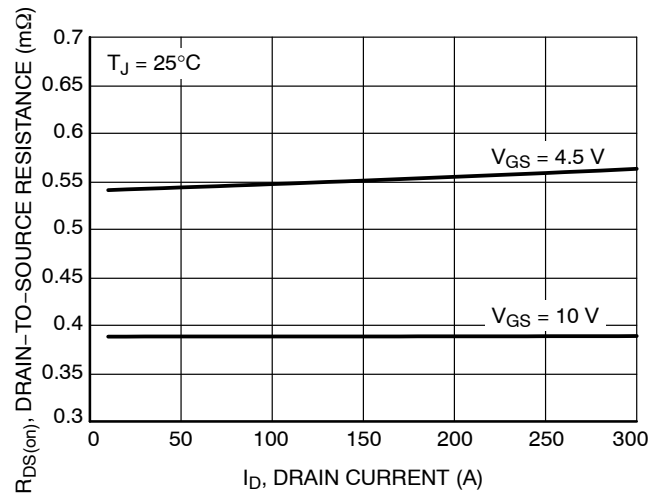


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

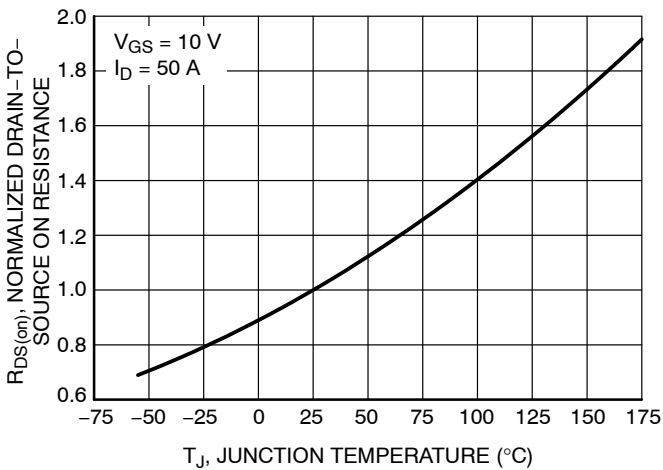


Figure 5. On-Resistance Variation with Temperature

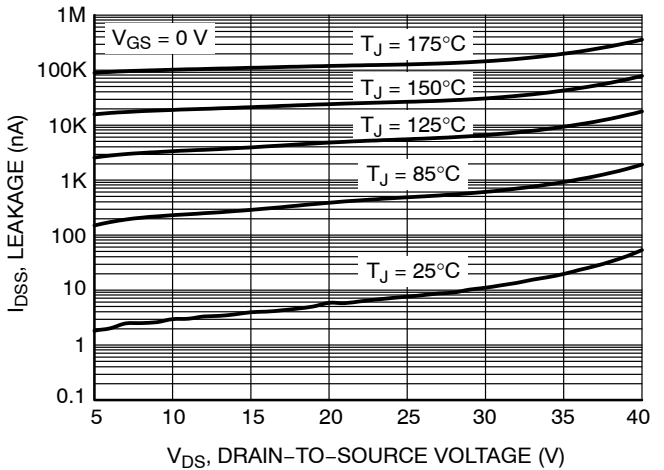


Figure 6. Drain-to-Source Leakage Current vs. Voltage

# NTMFS0D5N04XL

## TYPICAL CHARACTERISTICS

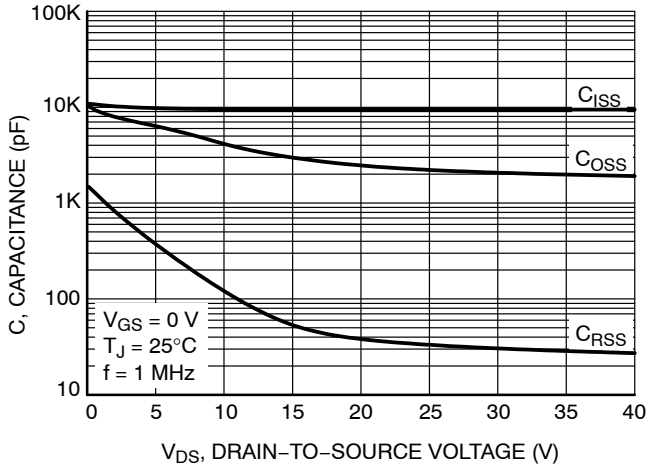


Figure 7. Capacitance Variation

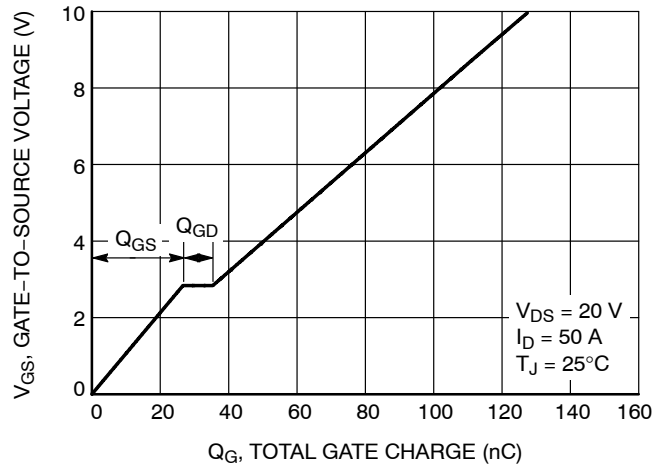


Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

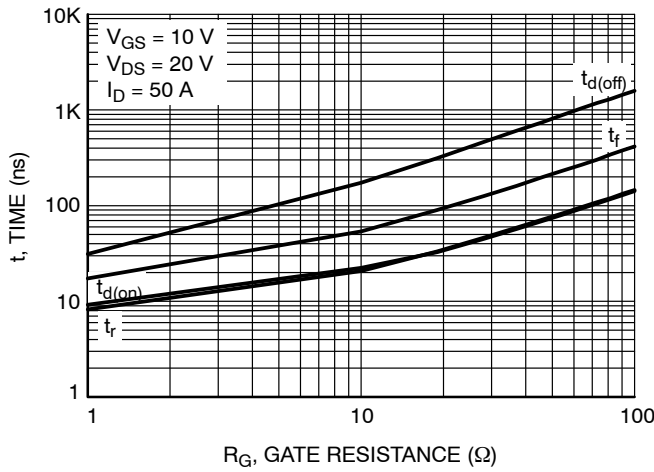


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

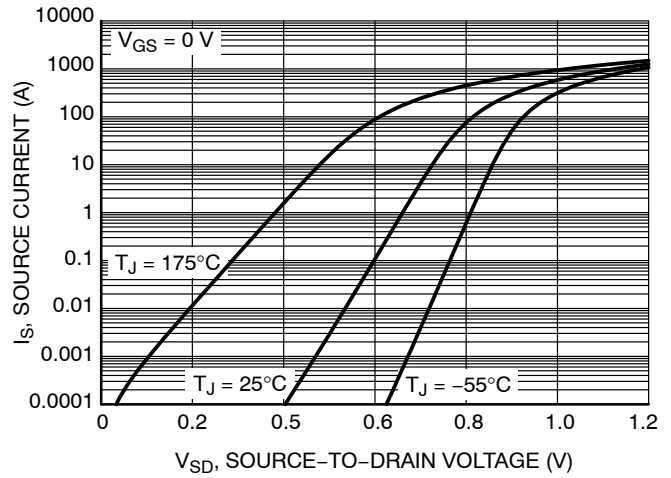


Figure 10. Diode Forward Voltage vs. Current

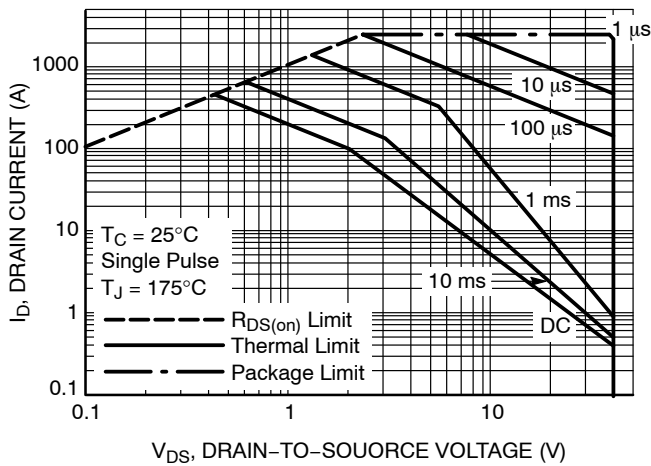


Figure 11. Safe Operating Area (SOA)

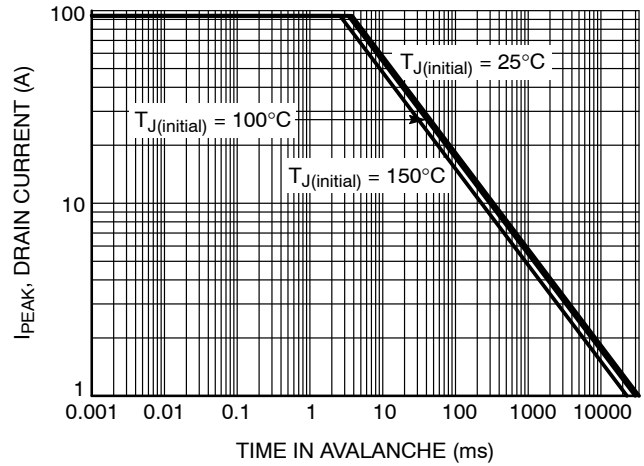
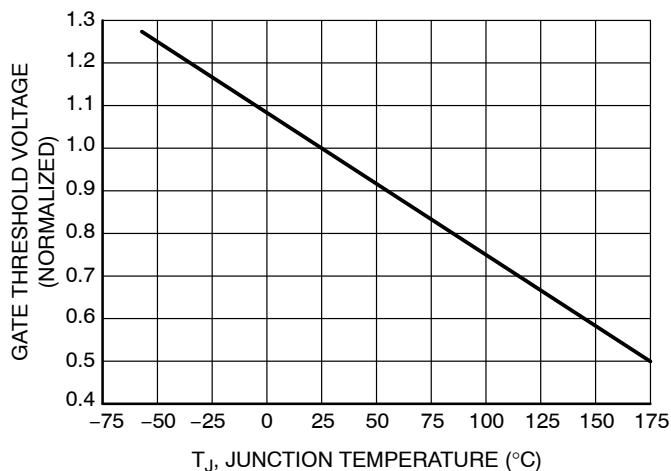


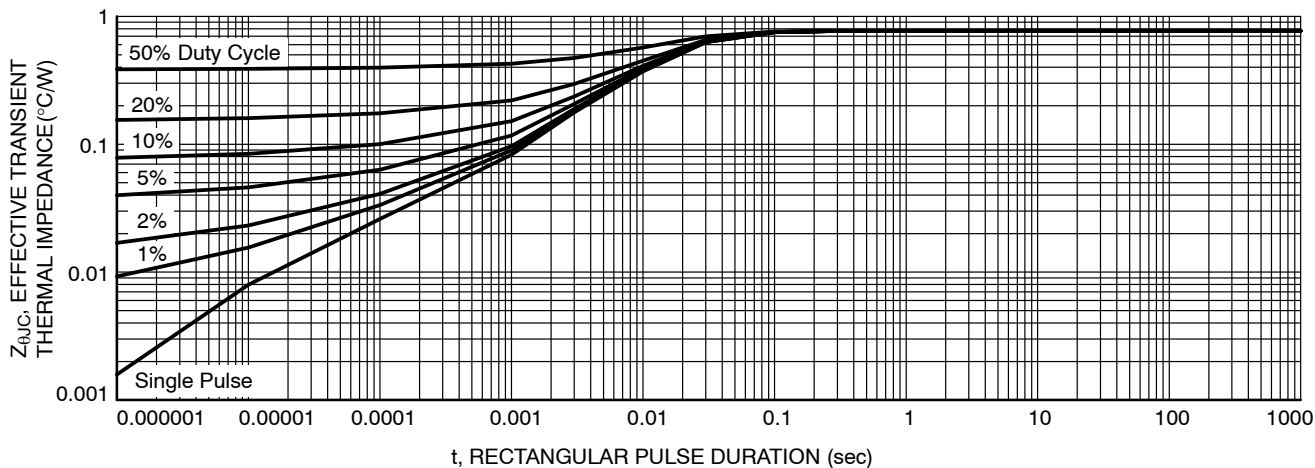
Figure 12. Avalanche Current vs. Pulse Time (UIS)

# NTMFS0D5N04XL

## TYPICAL CHARACTERISTICS



**Figure 13. Gate Threshold Voltage vs. Junction Temperature**

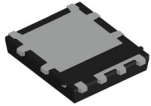


**Figure 14. Thermal Characteristics**

### DEVICE ORDERING INFORMATION

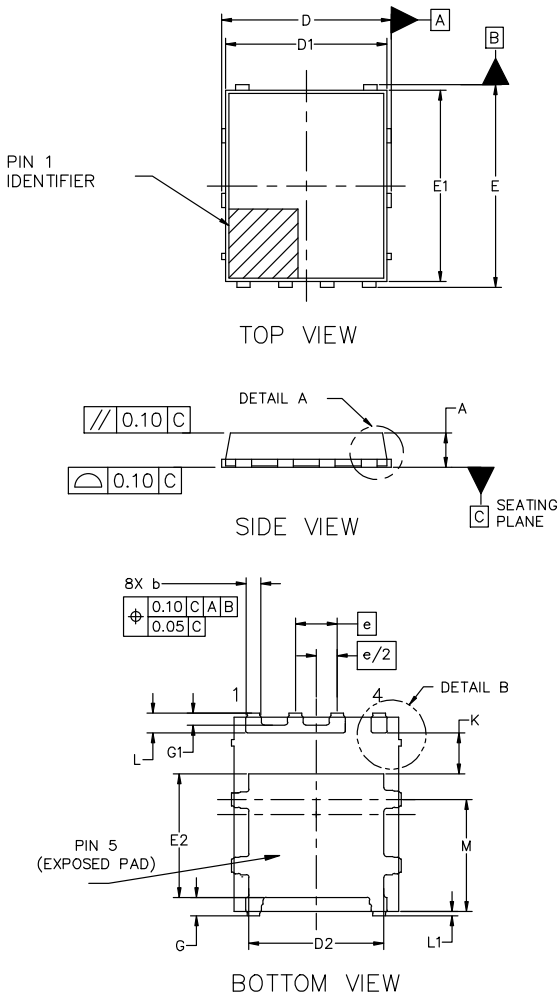
Device	Marking	Package	Shipping†
NTMFS0D5N04XLT1G	0D5N4L	DFNW5 (Pb-Free)	1500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



**DFN5 5.00x5.90x1.00, 1.27P**  
CASE 506FA  
ISSUE A

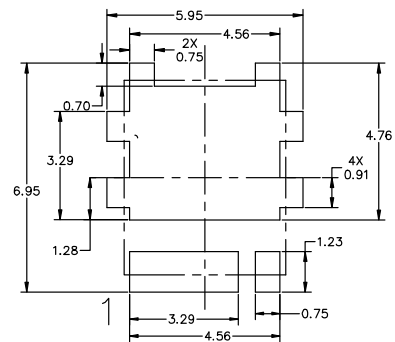
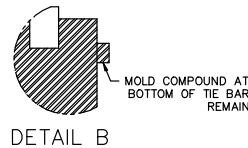
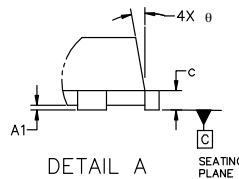
DATE 03 OCT 2024



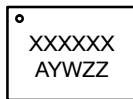
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.00	---	0.05
b	0.33	0.41	0.51
c	0.23	0.28	0.33
D	5.00	5.15	5.30
D1	4.80	5.00	5.20
D2	3.90	4.10	4.30
E	6.00	6.15	6.30
E1	5.70	5.90	6.10
E2	3.55	3.75	3.95
e	1.27 BSC		
G	0.50	0.55	0.70
G1	0.26	0.36	0.46
k	1.10	1.25	1.40
L	0.50	0.60	0.70
L1	0.150 REF		
M	3.00	3.40	3.80
θ	0°	---	12°



**GENERIC MARKING DIAGRAM\***



XXXX = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 W = Work Week  
 ZZ = Assembly Lot Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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<b>DESCRIPTION:</b>	<b>DFN5 5.00x5.90x1.00, 1.27P</b>	<b>PAGE 1 OF 1</b>

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